

FORBES

UNITED STATES DEPARTMENT OF COMMERCE Patent and Trademark Offic

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FILING DATE FIRST NAMED INVENTOR ATTORNEY DOCKET NO.

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SCHWEGMAN LUNDBERG WOESSNER & KLUTH

07/29/97

MINNEAPOLIS MN 55402

APPLICATION NO.

08/903,486

MINTEL W

2811
DATE MAILED:

12/21/00

303.326US1

Please find below and/or attached an Office communication concerning this application or the proceeding.

Commissioner of Patents and Trad marks

Office Action Summary	Application No. 08/903486	Applicant(s) Forbes
	Examiner William	Mintel 2811
The MAILING DATE of this communication appe	ears on the cover sh	eet beneath the correspondence address—
P ri d for Reply	フ	,
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET OF THIS COMMUNICATION.	TO EXPIRE	MONTH(S) FROM THE MAILING DATE
 Extensions of time may be available under the provisions of 37 CFF from the mailing date of this communication. If the period for reply specified above is less than thirty (30) days, a If NO period for reply is specified above, such period shall, by defaulting to reply within the set or extended period for reply will, by st 	reply within the statutory ult, expire SIX (6) MONTH	minimum of thirty (30) days will be considered timely. 4S from the mailing date of this communication.
Status	/	
Responsive to communication(s) filed on	10/00	
☐ This action is FINAL.	/	•
 Since this application is in condition for allowance exce accordance with the practice under Ex parte Quayle, 19 	935 C.D. 1 1; 453 O.G	ā. 213.
Disposition of Claims	37-48,	
A Claim(s) 1-5, 8-15, 22,	24-29.31-	is/are pending in the application.
•		
Of the above claim(s)	7/-7	is/are withdrawn from consideration.
& Claim(s) 1/-15, 23, 24-29 & Claim(s) 1-5, 8-10, 37-48	51 33	is/are allowed.
Claim(s) 7 3 7 - 98	30 J	is/are rejected.
□ Claim(s)		is/are objected to.
☐ Claim(s)	V	are subject to restriction or election requirement.
Application Papers		·
☐ See the attached Notice of Draftsperson's Patent Draw	ing Review, PTO-948	
☐ The proposed drawing correction, filed on	is 🗆 approv	ved 🗆 disapproved.
☐ The drawing(s) filed on is/are obj	ected to by the Exami	ner.
☐ The specification is objected to by the Examiner.		
☐ The oath or declaration is objected to by the Examiner.		
Pri rity under 35 U.S.C. § 119 (a)-(d)		
 □ Acknowledgment is made of a claim for foreign priority □ All □ Some* □ None of the CERTIFIED copies of received. 	of the priority docume	nts have been
 □ received in Application No. (Series Code/Serial Num □ received in this national stage application from the It 		
*Certified copies not received:		
Attachment(s)		
☑nformation Disclosure Statement(s), PTO-1449, Paper	No(s) 22	☐ Interview Summary, PTO-413
momation Disclosure Statement(s), F10-1449, Paper	140(5)	□ interview Summary, FTO-413
•		Motion of Informal Patent Application PTO 1
Notice of Reference(s) Cited, PTO-892 □ Notice of Draftsperson's Patent Drawing Review, PTO-		☐ Notice of Informal Patent Application, PTO-1

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The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1, 2, 8-10 are rejected under 35 U.S.C. 103(a) as being unpatentable over Halvis et al, (040) in view of the Admitted PriorArt..

In re claim 1, lines 1-5, the Abstract of Halvis at lines 1-4 discloses a polysilicon gate with 10% carbon. In re claim 1, line 5, column 4, lines 25-35, recite that the gates are interconnected to a driving voltage. Halvis lacks the underlying insulated portion of line 3, claim 1.

Applicant's specification at page 2, line 5, teaches SOI technology for polysilicon gate FET's. Therefore, in re claim 1, it would have been obvious to place the FET's of Halvis on an insulating layer in order to, for example, improve device insolation. In re claim 2, Halvis recites polysilicon. In re claims 8-10, column 4, lines 10-20, recites silicon dioxide 42 and column 4, line 3, recites silicon dioxide 32.

Claims 3-5, 37-48, 50-53 are rejected under 35 U.S.C. 103(a) as being unpatentable over Halvis in view of the Admitted Prior Art as applied to claim 1, 2, 8-10 above, and further in view of Demichelis et al.

Halvis is described above but lacks explicit microcrystalline SiC. Demichelis at column 1, page 1327, lines 20-36, teaches microcrystalline SiC as having increased electrical conductivity without significantly changing the optical properties. Therefore, in re claim 3, it would have been

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obvious to replace the polycrystalline SiC of Halvis with microcrystalline SiC. In re claims 4-5, Demichelis at page 1327,k column 1, first paragraph, teaches p and n doped SiC as having increased electrical conductivity. Claims 37-48, 50-53 are rejected as above.

Claims 11-15, 22, 24-29, 31-35 are allowed over the art of record because the art does not disclose complementary FET's or memory devices using the claimed material.

Applicant's arguments with respect to claims 1-5, 8-10, 37-48, 50-53 have been considered but are most in view of the new ground(s) of rejection.

Characterized as merely of background interest are the ten newly submitted references.

Cited for SiC gates are Japan (191) + (960),

Any inquiry concerning this communication or earlier communications from the examiner should be directed to W. Mintel whose telephone number is (703) 308-4916. The examiner can normally be reached on M-Th from 8:30 to 5:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Tom Thomas, can be reached on (703) 308-2772. The fax phone number for the organization where this application or proceeding is assigned is (703) 308-7722.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

Mintel/tr

12-18-00

William Mintel
William Mintel
Primary Examiner
Art Unit 2811